C3M0015065D

Silicon Carbide Power MOSFET
C3M™ MOSFET Technology
N-Channel Enhancement Mode

Features

- 3rd Generation SiC MOSFET technology
- High blocking voltage with low on-resistance
- High speed switching with low capacitances
- Fast intrinsic diode with low reverse recovery (Qrr)
- Halogen free, RoHS compliant

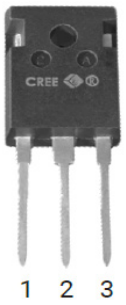
Benefits

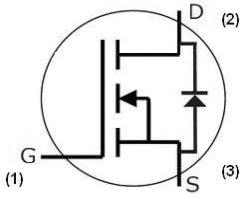
- Higher system efficiency
- Reduced cooling requirements
- Increased power density
- Increased system switching frequency
- Easy to parallel and simple to drive
- Enable new hard switching PFC topologies (Totem-Pole)

Applications

- EV charging
- Solar PV Inverters
- UPS
- SMPS
- DC/DC converters

Package





Part Number	Package	Marking
C3M0015065D	TO-247-3	C3M0015065D

Maximum Ratings (T_C=25˚C, unless otherwise specified)

Symbol	Parameter	Value	Unit	Note
V_{DSmax}	Drain - Source Voltage	650	V	
V_{GSmax}	Gate - Source voltage	-8/+19	V	Note 1
I_D	Continuous Drain Current, V_{GS} = 15 V, T_C = 25˚C	120	A	Fig. 19 Note 2
	Continuous Drain Current, V_{GS} = 15 V, T_C = 100˚C	96		
$I_{D(pulse)}$	Pulsed Drain Current, Pulse width t_P limited by T_{jmax}	418	A	
P_D	Power Dissipation, T_C=25˚C, T_J = 175 ˚C	416	W	Fig. 20
T_J , T_{stg}	Operating Junction and Storage Temperature	-40 to +175	˚C	
T_L	Solder Temperature, 1.6mm (0.063") from case for 10s	260	˚C	
M_d	Mounting Torque, (M3 or 6-32 screw)	1 8.8	Nm lbf-in	

Note (1): Recommended turn off / turn on gate voltage V_{GS} - 4V...0V / +15V
Note (2): Package limited to 120 A

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Electrical Characteristics (T_C = 25˚C unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions	Note
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	650			V	V_{GS} = 0 V, I_D = 100 µA	
$V_{GS(th)}$	Gate Threshold Voltage	1.8	2.3	3.6	V	V_{DS} = V_{GS}, I_D = 15.5 mA	Fig. 11
			1.9		V	V_{DS} = V_{GS}, I_D = 15.5 mA, T_J = 175ºC	
I_{DSS}	Zero Gate Voltage Drain Current		1	50	µA	V_{DS} = 650 V, V_{GS} = 0 V	
I_{GSS}	Gate-Source Leakage Current		10	250	nA	V_{GS} = 15 V, V_{DS} = 0 V	
$R_{DS(on)}$	Drain-Source On-State Resistance	10.5	15	21	mΩ	V_{GS} = 15 V, I_D = 55.8A	Fig. 4, 5,6
			20			V_{GS} = 15 V, I_D = 55.8A, T_J = 175ºC	
g_{fs}	Transconductance		42		S	V_{DS}= 20 V, I_{DS}= 55.8 A	Fig. 7
			40			V_{DS}= 20 V, I_{DS}= 55.8 A, T_J = 175ºC	
C_{iss}	Input Capacitance		5011		pF	V_{GS} = 0 V, V_{DS} = 400 V f = 100 Khz V_{AC} = 25 mV	Fig. 17, 18
C_{oss}	Output Capacitance		289				
C_{rss}	Reverse Transfer Capacitance		31				
$C_{o(er)}$	Effective Output Capacitance (Energy Related)		357				Note: 3
$C_{o(tr)}$	Effective Output Capacitance (Time Related)		516				Note: 3
E_{oss}	C_{oss} Stored Energy		29		µJ		Fig. 16
E_{ON}	Turn-On Switching Energy (Body Diode)		1500		µJ	V_{DS} = 400 V, V_{GS} = -4 V/15 V, I_D = 55.8 A, $R_{G(ext)}$ = 5 Ω, L= 57.6 µH, T_J = 175ºC FWD = Internal Body Diode of MOSFET	Fig. 25
E_{OFF}	Turn Off Switching Energy (Body Diode)		700				
E_{ON}	Turn-On Switching Energy (External Diode)		1200		µJ	V_{DS} = 400 V, V_{GS} = -4 V/15 V, I_D = 55.8 A, $R_{G(ext)}$ = 5 Ω, L= 57.6 µH, T_J = 175ºC FWD = External SiC DIODE	Fig. 25
E_{OFF}	Turn Off Switching Energy (External Diode)		1000				
$t_{d(on)}$	Turn-On Delay Time		22		ns	V_{DD} = 400 V, V_{GS} = -4 V/15 V I_D = 55.8 A, $R_{G(ext)}$ = 5 Ω, L= 57.6 µH Timing relative to V_{DS} Inductive load	Fig. 26
t_r	Rise Time		125				
$t_{d(off)}$	Turn-Off Delay Time		58				
t_f	Fall Time		25				
$R_{G(int)}$	Internal Gate Resistance		1.5		Ω	f = 1 MHz, V_{AC} = 25 mV	
Q_{gs}	Gate to Source Charge		54		nC	V_{DS} = 400 V, V_{GS} = -4 V/15 V I_D = 55.8 A Per IEC60747-8-4 pg 21	Fig. 12
Q_{gd}	Gate to Drain Charge		62				
Q_g	Total Gate Charge		188				

Note (3): $C_{o(er)}$, a lumped capacitance that gives same stored energy as Coss while Vds is rising from 0 to 400V
$C_{o(tr)}$, a lumped capacitance that gives same charging time as Coss while Vds is rising from 0 to 400V

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Reverse Diode Characteristics (T_C = 25˚C unless otherwise specified)

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_{SD}	Diode Forward Voltage	4.7		V	V_{GS} = -4 V, I_{SD} = 27.9 A, T_J = 25 °C	Fig. 8, 9, 10
		4.2		V	V_{GS} = -4 V, I_{SD} = 27.9 A, T_J = 175 °C	
I_S	Continuous Diode Forward Current		79	A	V_{GS} = -4 V, T_C = 25˚C	
$I_{S, pulse}$	Diode pulse Current		418	A	V_{GS} = -4 V, pulse width t_p limited by T_{jmax}	
t_{rr}	Reverse Recovery time	85		ns	V_{GS} = -4 V, I_{SD} = 55.8 A, V_R = 400 V dif/dt = 1500 A/µs, T_J = 175 °C	
Q_{rr}	Reverse Recovery Charge	667		nC		
I_{rrm}	Peak Reverse Recovery Current	17		A		
t_{rr}	Reverse Recovery time	74		ns	V_{GS} = -4 V, I_{SD} = 55.8 A, V_R = 400 V dif/dt = 1000 A/µs, T_J = 175 °C	
Q_{rr}	Reverse Recovery Charge	562		nC		
I_{rrm}	Peak Reverse Recovery Current	14		A		

Thermal Characteristics

Symbol	Parameter	Typ.	Unit	Test Conditions	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	0.35	°C/W		Fig. 21
$R_{\theta JA}$	Thermal Resistance From Junction to Ambient	40			

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Typical Performance

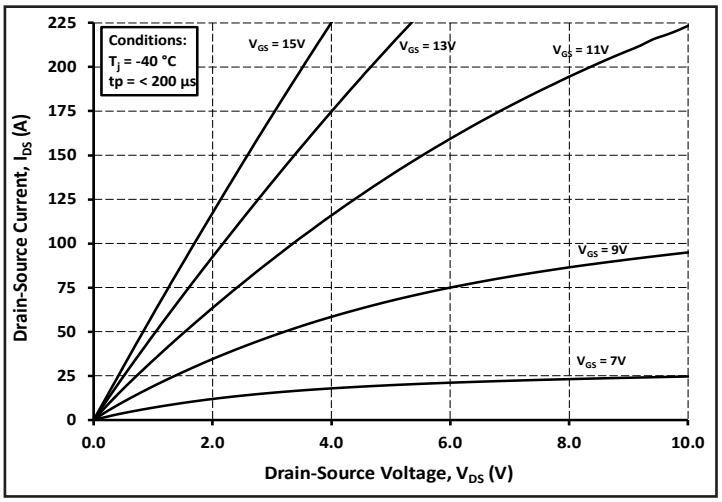

Figure 1. Output Characteristics T_J = -40 °C

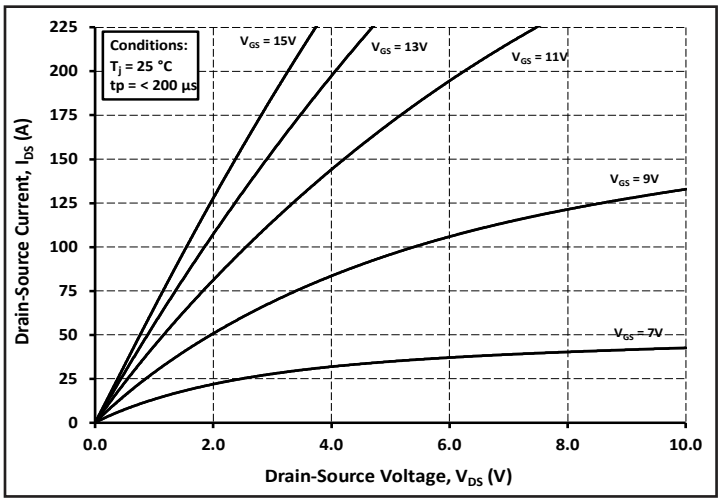

Figure 2. Output Characteristics T_J = 25 °C

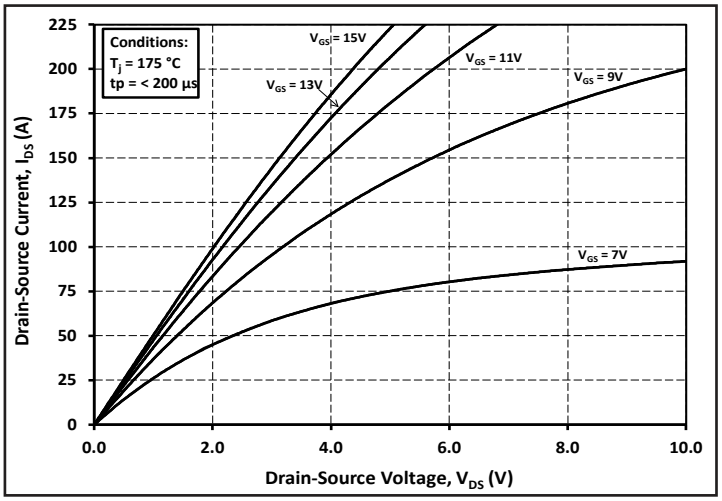

Figure 3. Output Characteristics T_J = 175 °C

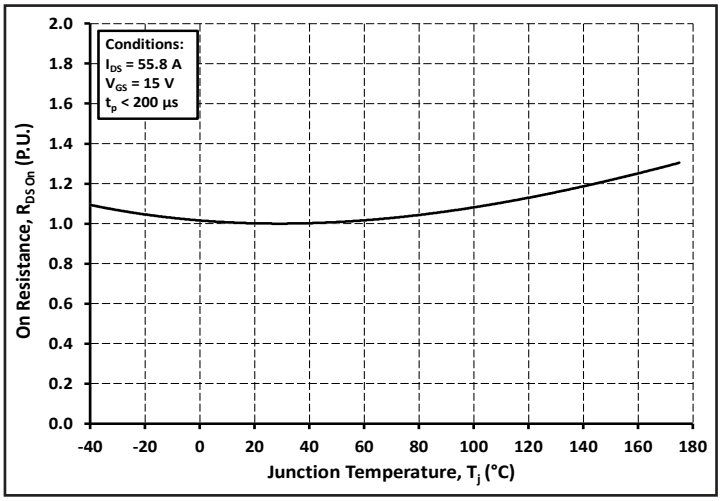

Figure 4. Normalized On-Resistance vs. Temperature

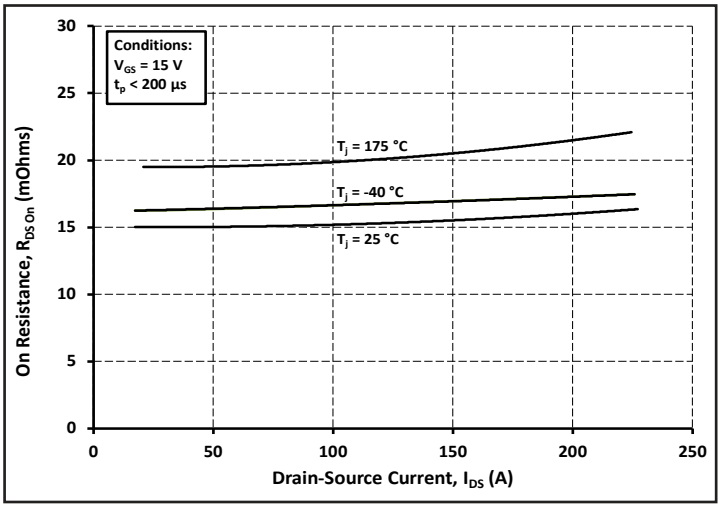

Figure 5. On-Resistance vs. Drain Current
For Various Temperatures

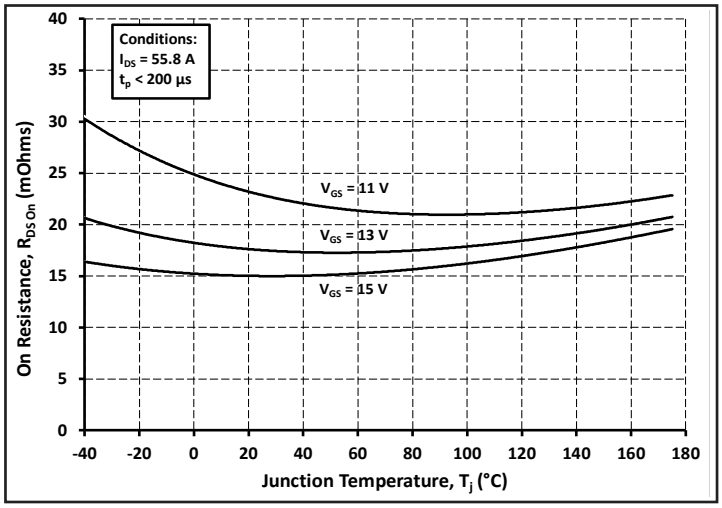

Figure 6. On-Resistance vs. Temperature
For Various Gate Voltage

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Typical Performance

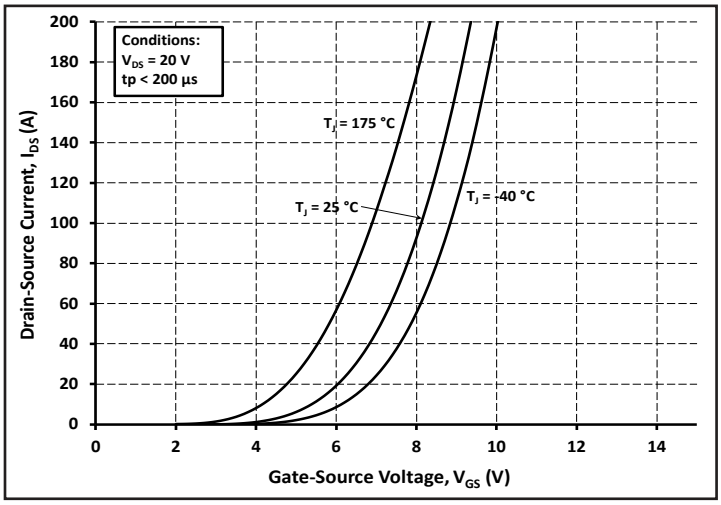

Figure 7. Transfer Characteristic for Various Junction Temperatures

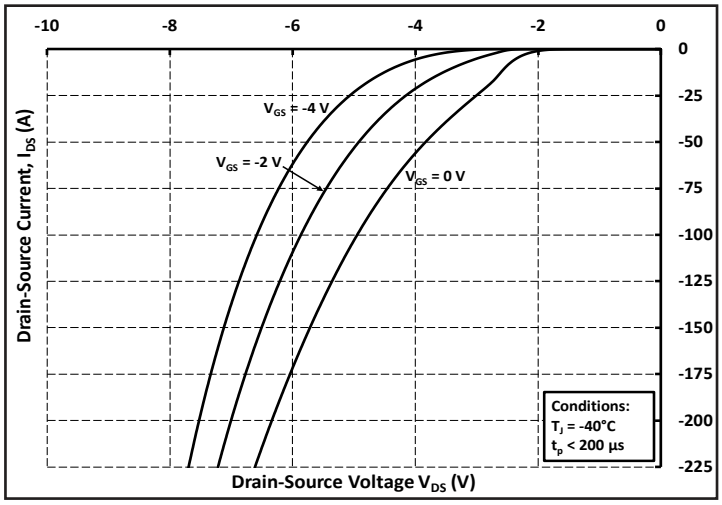

Figure 8. Body Diode Characteristic at -40 °C

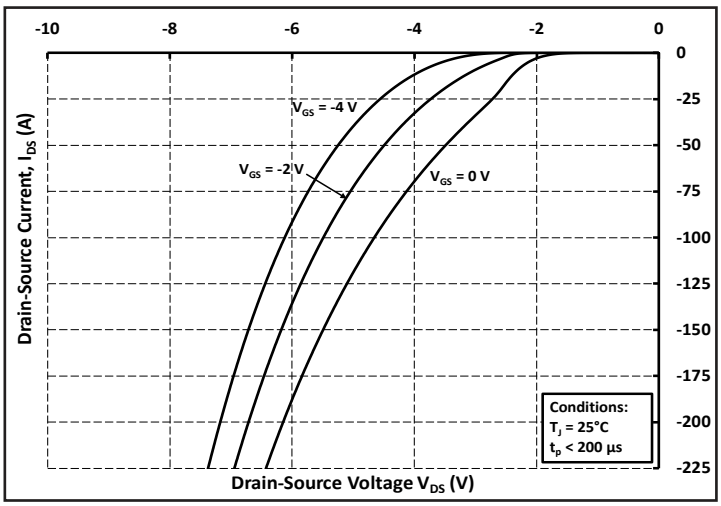

Figure 9. Body Diode Characteristic at 25 °C

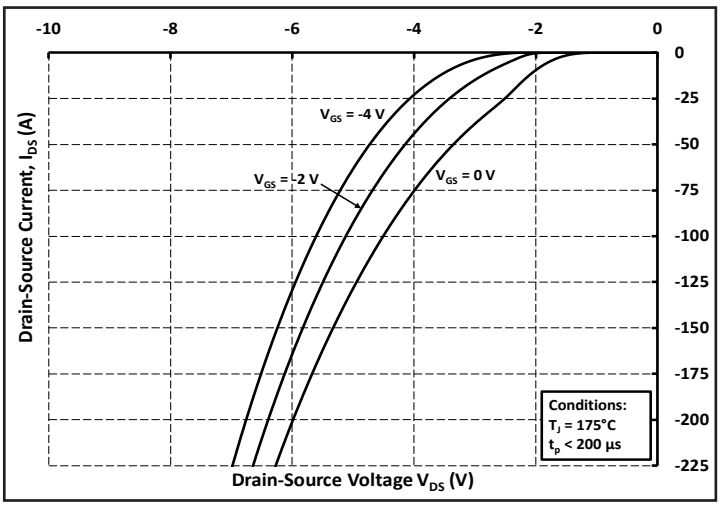

Figure 10. Body Diode Characteristic at 175 °C

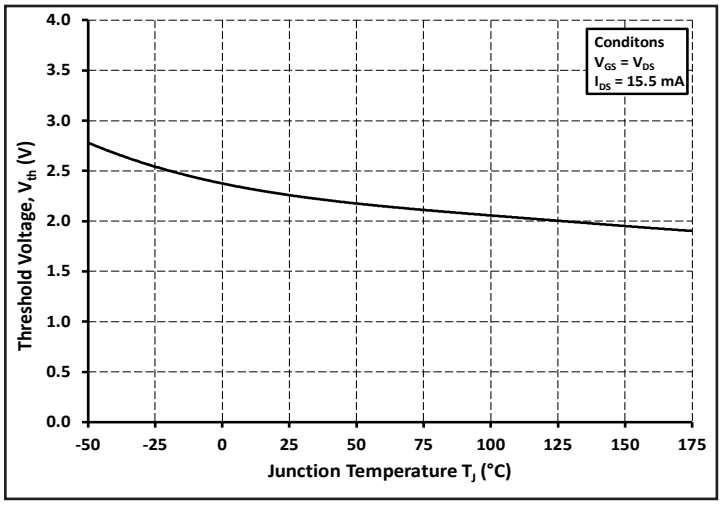

Figure 11. Threshold Voltage vs. Temperature

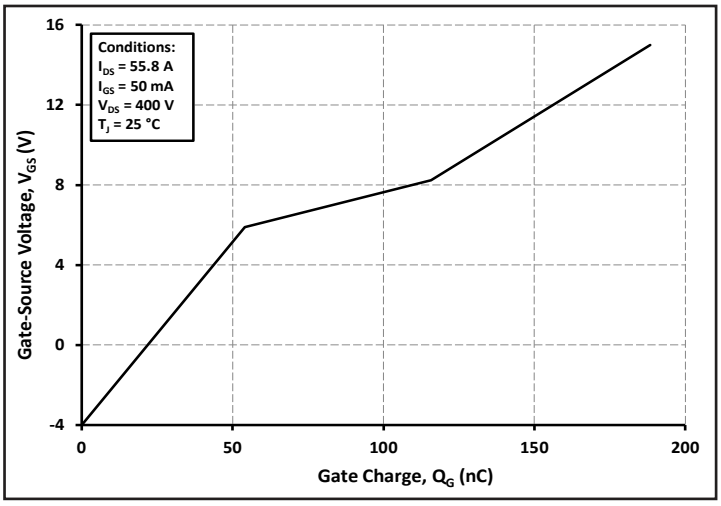

Figure 12. Gate Charge Characteristics

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Typical Performance

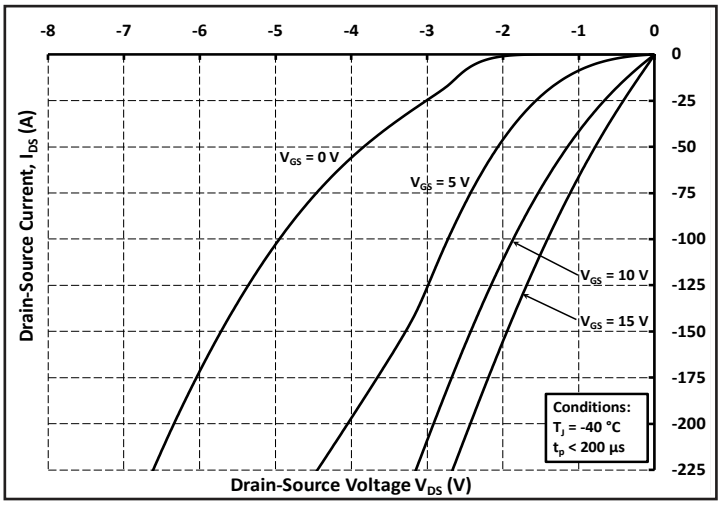

Figure 13. 3rd Quadrant Characteristic at -40 °C

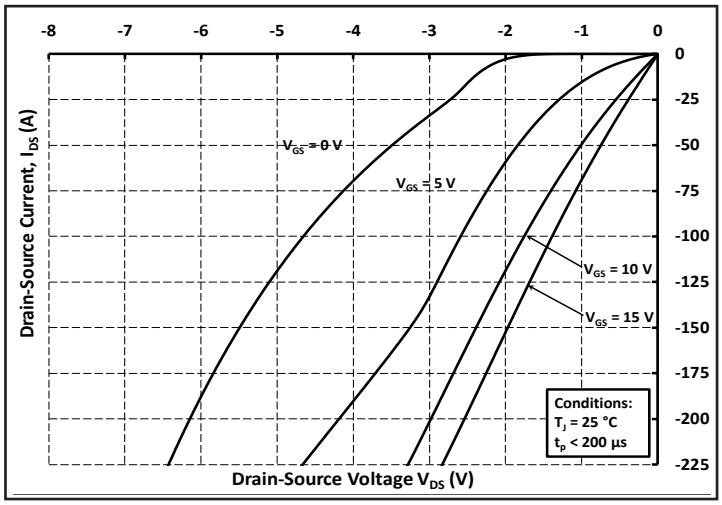

Figure 14. 3rd Quadrant Characteristic at 25 °C

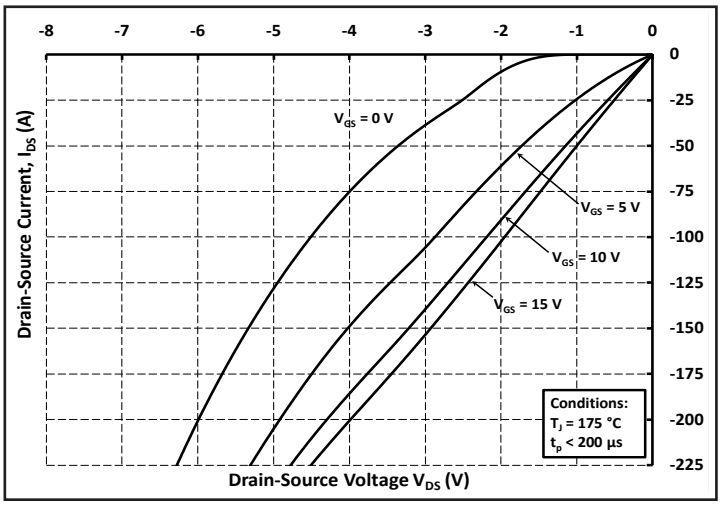

Figure 15. 3rd Quadrant Characteristic at 175 °C

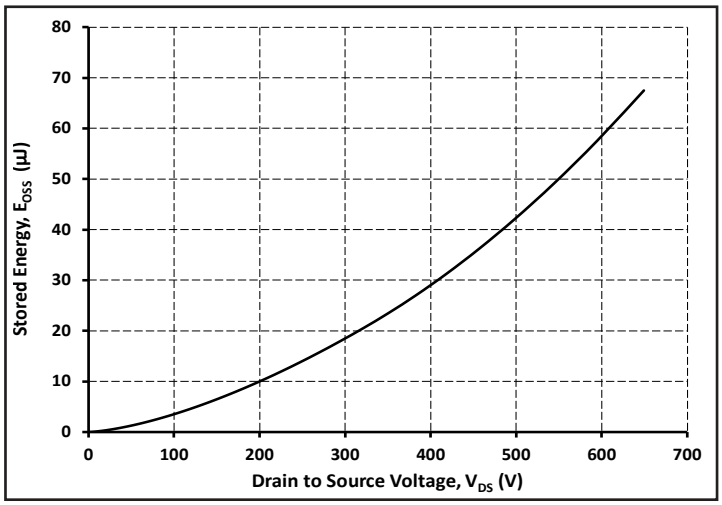

Figure 16. Output Capacitor Stored Energy

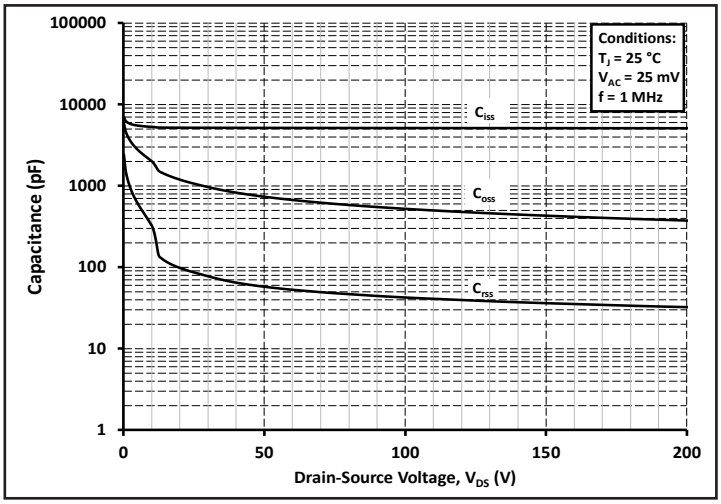

Figure 17. Capacitances vs. Drain-Source Voltage (0 - 200V)

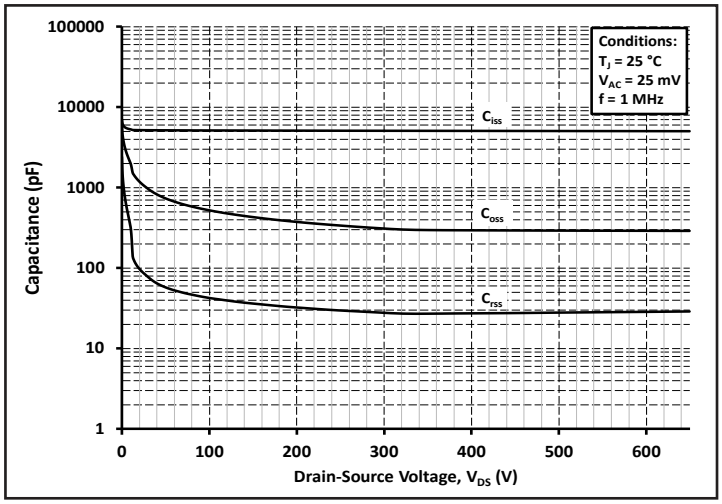

Figure 18. Capacitances vs. Drain-Source Voltage (0 - 650V)

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Typical Performance

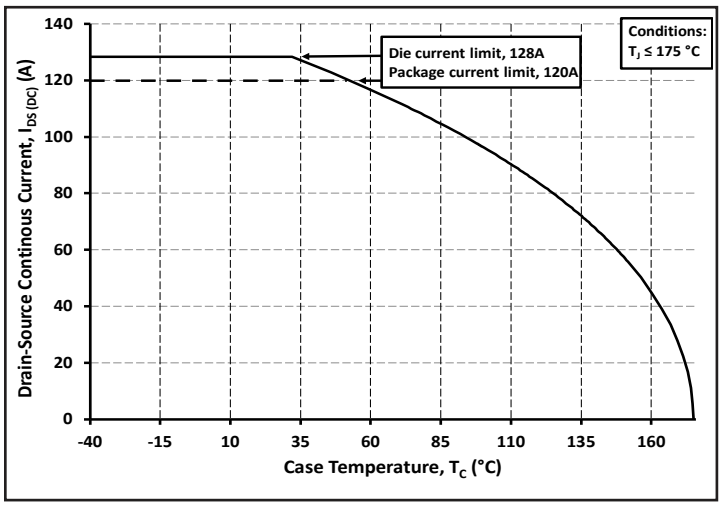

Figure 19. Continuous Drain Current Derating vs. Case Temperature

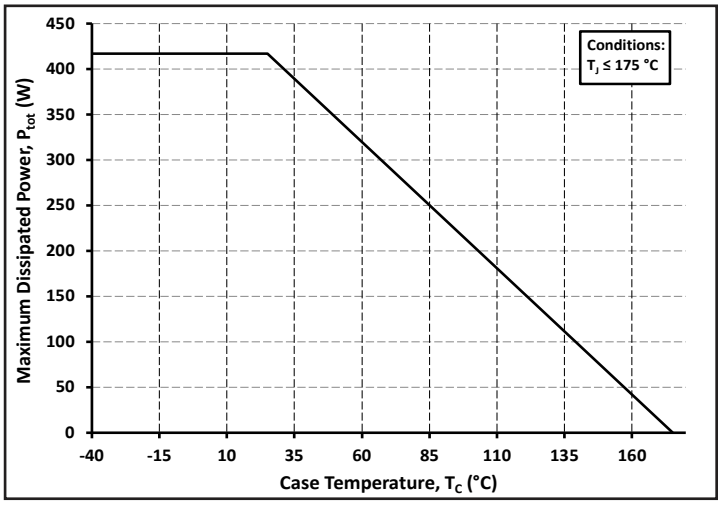

Figure 20. Maximum Power Dissipation Derating vs. Case Temperature

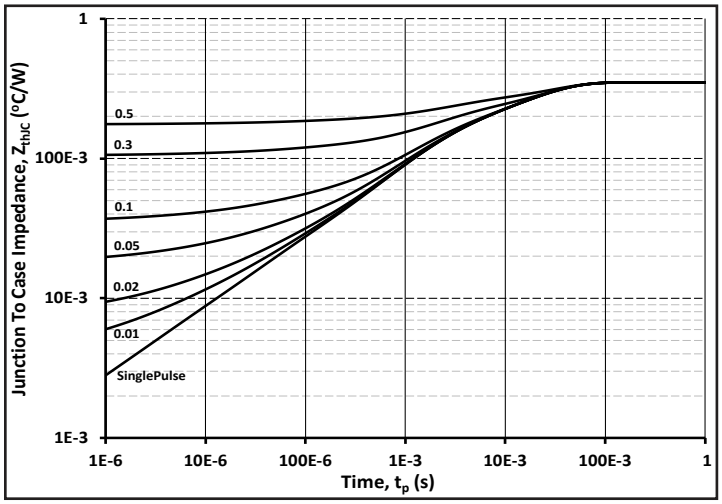

Figure 21. Transient Thermal Impedance (Junction - Case)

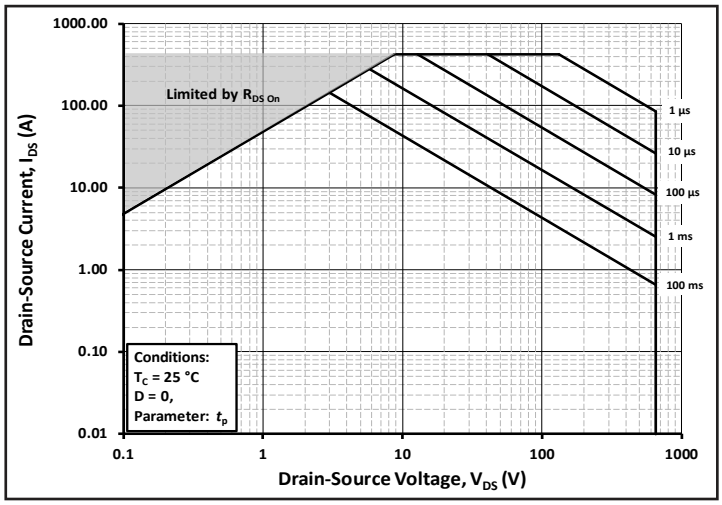

Figure 22. Safe Operating Area

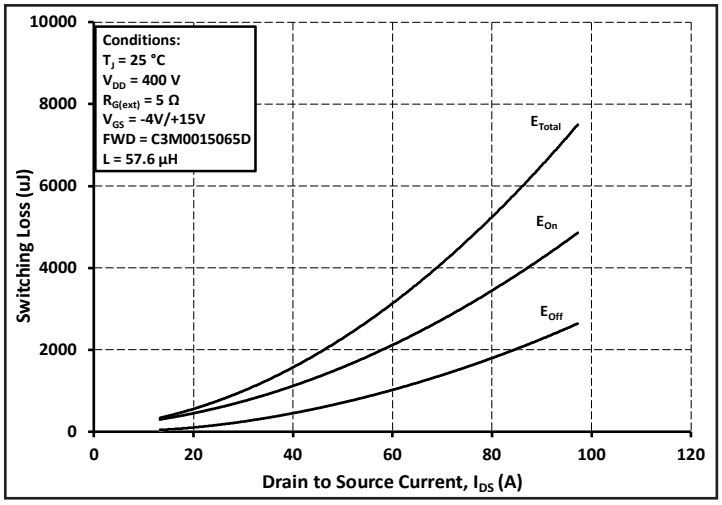

Figure 23. Clamped Inductive Switching Energy vs. Drain Current (V_{DD} = 400V)

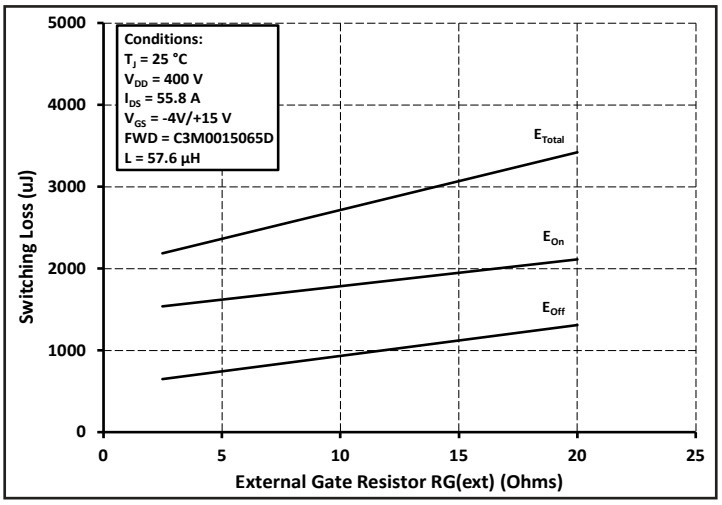

Figure 24. Clamped Inductive Switching Energy vs. $R_{G(ext)}$

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Typical Performance

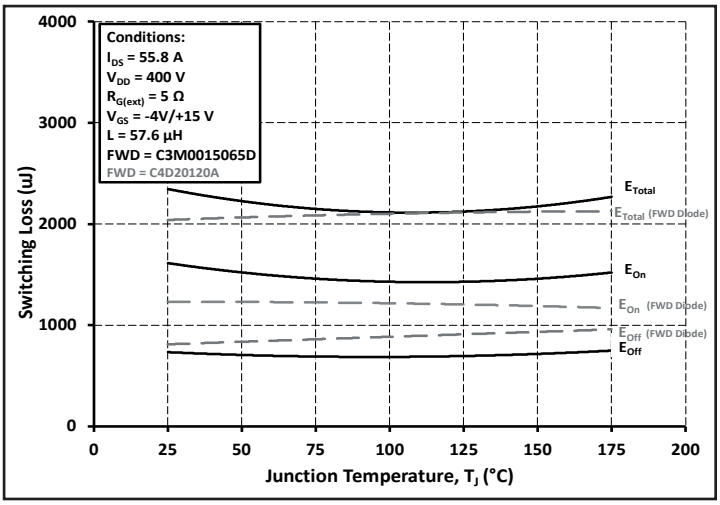

Figure 25. Clamped Inductive Switching Energy vs. Temperature

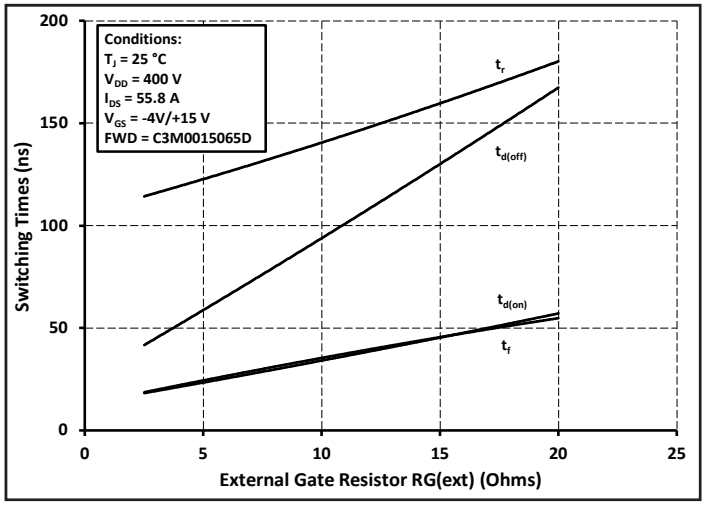

Figure 26. Switching Times vs. $R_{G(ext)}$

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Test Circuit Schematic

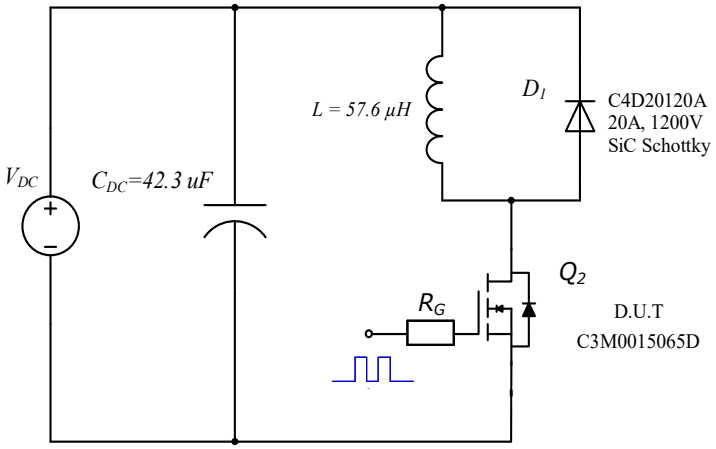

Figure 27. Clamped Inductive Switching Waveform Test Circuit

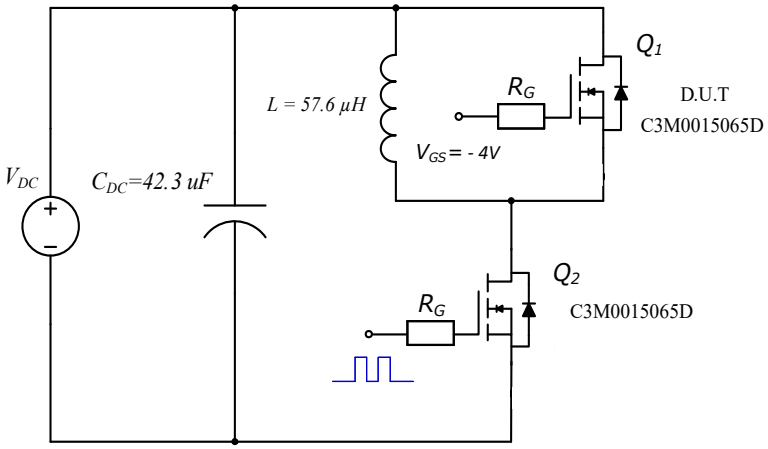

Figure 28. Body Diode Recovery Test Circuit

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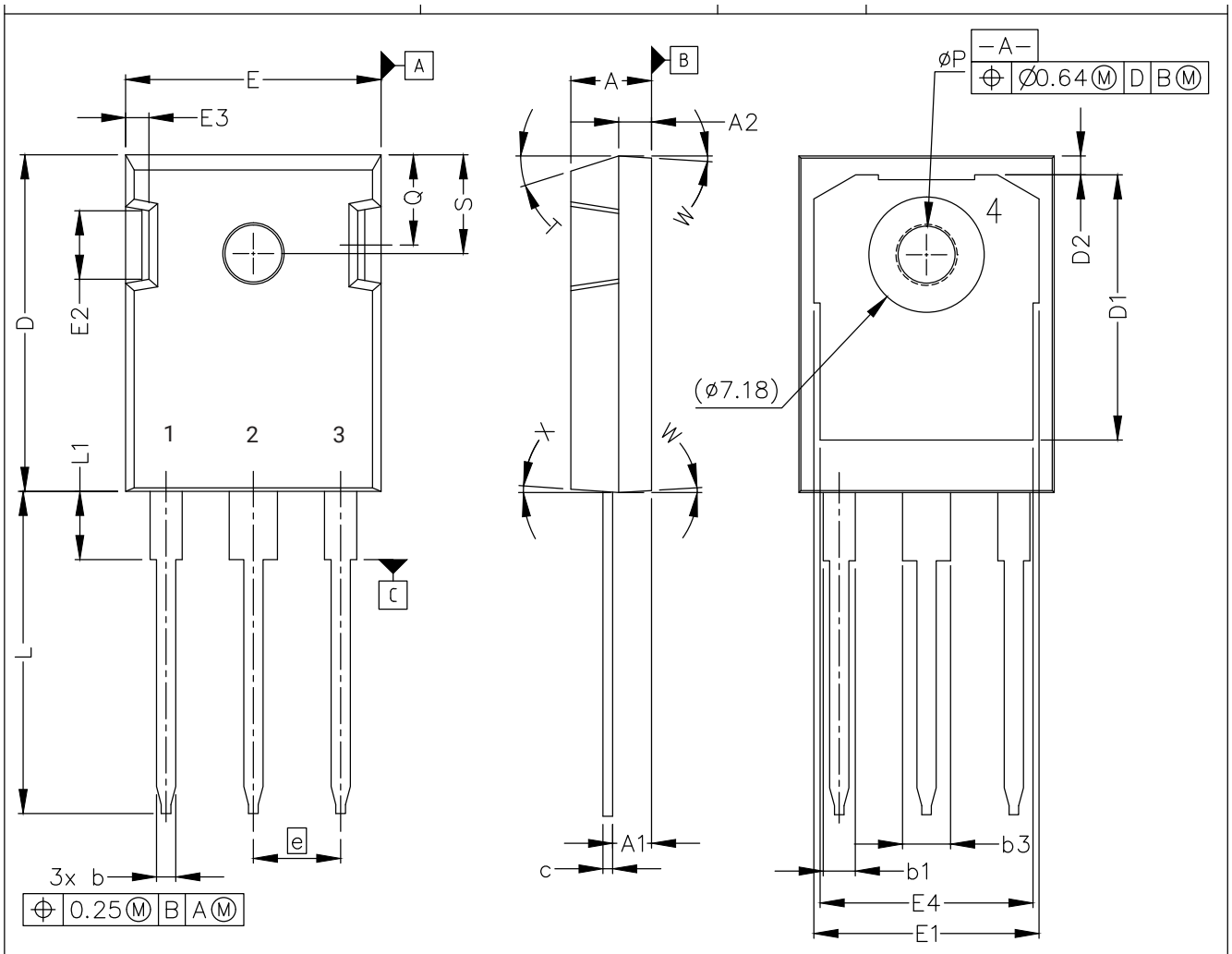
Package Dimensions

Package TO-247-3



NOTE ;
1. ALL METAL SURFACES: TIN PLATED,EXCEPT AREA OF CUT
2. DIMENSIONING & TOLERANCEING CONFIRM TO ASME Y14.5M-1994.
3. ALL DIMENSIONS ARE IN MILLIMETERS. ANGLES ARE IN DEGREES.
4. THIS DRAWING WILL MEET ALL DIMENSIONS REQUIREMENT OF JEDEC outlines TO-247 AD.
5. DIMENSION DO NOT INCLUDE BURR OR MOLD FLASH.

1 - GATE
2 - DRAIN (COLLECTOR)
3 - SOURCE (EMITTER)
4 - DRAIN (COLLECTOR)

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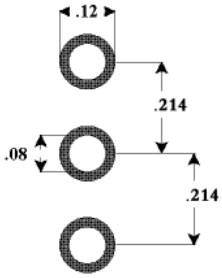
Package Dimensions

Package TO-247-3

SYM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.83	5.21	.190	.205
A1	2.29	2.54	.090	.100
A2	1.91	2.16	.075	.085
b	1.07	1.33	.042	.052
b1	1.91	2.41	.075	.095
b3	2.87	3.38	.113	.133
c	0.55	0.68	.022	.027
D	20.80	21.10	.819	.831
D1	16.25	17.65	.640	.695
D2	0.95	1.25	.037	.049
E	15.75	16.13	.620	.635
E1	13.10	14.15	.516	.557
E2	3.68	5.10	.145	.201
E3	1.00	1.90	.039	.075
E4	12.38	13.43	.487	.529
e	5.44 BSC		.214 BSC	
N	3		3	
L	19.81	20.32	.780	.800
L1	4.10	4.40	.161	.173
ϕP	3.51	3.65	.138	.144
Q	5.49	6.00	.216	.236
S	6.04	6.30	.238	.248
T	17.5° REF.			
W	3.5° REF.			
X	4° REF.			

Recommended Solder Pad Layout



TO-247-3

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